IXYS UK WESTCODE

Date:- 1st June, 2015

Data Sheet Issue:- P2

Phase Control Thyristor
Types N4650EA400 & N4650EA450

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	4000-4500	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	4000-4500	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	4000-4500	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	4100-4600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{T(AV)}$	Mean on-state current. T_{sink}=55°C, (note 2)	4650	A
$I_{T(AV)}$	Mean on-state current. T_{sink}=85°C, (note 2)	3300	A
$I_{T(AV)}$	Mean on-state current. T_{sink}=85°C, (note 3)	1860	A
$I_{T(RMS)}$	Nominal RMS on-state current. T_{sink}=25°C, (note 2)	9010	A
$I_{T(d.c.)}$	D.C. on-state current. T_{sink}=25°C, (note 4)	8220	A
I_{TSM}	Peak non-repetitive surge t_p=10ms, V_{RM}=0.6V_{RRM}, (note 5)	56	kA
I_{TSM2}	Peak non-repetitive surge t_p=10ms, $V_{RM}\leq$10V, (note 5)	62	kA
I^2t	I^2t capacity for fusing t_p=10ms, V_{RM}=0.6V_{RRM}, (note 5)	15.7×10^6	A^2s
I^2t	I^2t capacity for fusing t_p=10ms, $V_{RM}\leq$10V, (note 5)	19.2×10^6	A^2s
di_T/dt	Maximum rate of rise of on-state current (repetitive), (Note 6)	150	A/µs
	Maximum rate of rise of on-state current (non-repetitive), (Note 6)	300	A/µs
V_{RGM}	Peak reverse gate voltage	5	V
$P_{G(AV)}$	Mean forward gate power	5	W
P_{GM}	Peak forward gate power	30	W
V_{GD}	Non-trigger gate voltage, (Note 7)	0.25	V
T_{HS}	Operating temperature range	-40 to +125	°C
T_{stg}	Storage temperature range	-40 to +150	°C

Notes: -
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 125°C T_j initial.
6) V_D=67% V_{DRM}, I_{TM}=4000A, I_{FG}=2A, $t_r\leq$0.5µs, T_{case}=125°C.
7) Rated V_{DRM}.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{TM}	Maximum peak on-state voltage	-	-	1.70	I_{TM}=4000A	V
V_0	Threshold voltage	-	-	0.977		V
r_T	Slope resistance	-	-	0.177		mΩ
dv/dt	Critical rate of rise of off-state voltage	1000	-	-	V_D=80% V_{DRM}, Linear ramp, gate o/c	V/µs
I_{DRM}	Peak off-state current	-	-	200	Rated V_{DRM}	mA
I_{RRM}	Peak reverse current	-	-	200	Rated V_{RRM}	mA
V_{GT}	Gate trigger voltage	-	-	3.0	T_j=25°C, V_D=10V, I_T=3A	V
I_{GT}	Gate trigger current	-	-	300		mA
I_H	Holding current	-	-	1000	T_j=25°C	mA
t_{gd}	Gate controlled turn-on delay time	-	1.0	1.6	I_{FG}=2A, t_r=0.5µs, V_D=67%V_{DRM}, I_{TM}=2000A, di/dt=10A/µs, T_j=25°C	µs
t_{gt}	Turn-on time	-	3.5	5.0		
Q_{rr}	Recovered Charge	-	14900	16000	I_{TM}=2000A, t_p=2000µs, di/dt=10A/µs, V_r=100V	µC
Q_{ra}	Recovered Charge, 50% chord	-	8400	-		µC
I_{rm}	Reverse recovery current	-	295	-		A
t_{rr}	Reverse recovery time, 50% chord	-	57	-		µs
t_q	Turn-off time	-	750	-	I_{TM}=2000A, t_p=2000µs, di/dt=10A/µs, V_r=100V, V_{dr}=80%V_{DRM}, dV_{dr}/dt=20V/µs	µs
		-	1200	-	I_{TM}=2000A, t_p=2000µs, di/dt=10A/µs, V_r=100V, V_{dr}=80%V_{DRM}, dV_{dr}/dt=200V/µs	
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.005	Double side cooled	K/W
		-	-	0.012	Cathode side cooled	K/W
		-	-	0.009	Anode side cooled	K/W
F	Mounting force	76	-	93		kN
W_t	Weight	-	1.55	-		kg

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{DRM} V_{DSM} V_{RRM} V	V_{RSM} V	V_D V_R DC V
40	4000	4100	2400
45	4500	4600	2700

2.0 Extension of Voltage Grades

This report is applicable to other and higher voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Repetitive dv/dt

Standard dv/dt is 1000V/µs.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_0 + \sqrt{V_0 + 4 \cdot ff \cdot r_s \cdot W_{AV}}}{2 \cdot ff \cdot r_s}$$

and:

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_{Hs}$$

Where V_0=0.977V, r_T=0.177mΩ,

R_{th} = Supplementary thermal impedance, see table below.

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave Double Side Cooled	0.00556	0.00549	0.00543	0.00538	0.00527	0.00514	0.00500
Square wave Cathode Side Cooled	0.01292	0.01285	0.01278	0.01271	0.01259	0.01244	0.01200
Sine wave Double Side Cooled	0.00551	0.00543	0.00537	0.00531	0.00515		
Sine wave Cathode Side Cooled	0.01286	0.01277	0.01270	0.01263	0.01245		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.46	2.45	2	1.73	1.41	1.15	1
Sine wave	3.98	2.78	2.22	1.88	1.57		

5.2 Calculating V_T using ABCD Coefficients

The on-state characteristic I_T vs. V_T, on page 5 is represented in two ways;
(i) the well established V_o and r_s tangent used for rating purposes and
(ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_T in terms of I_T given below:

$$V_T = A + B \cdot \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_T agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		125°C Coefficients	
A	1.254701	A	0.9310573
B	7.754636×10^{-3}	B	-0.03021167
C	1.26163×10^{-4}	C	1.10532×10^{-4}
D	-3.395382×10^{-3}	D	9.124054×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where *p = 1* to *n, n* is the number of terms in the series and:

t = Duration of heating pulse in seconds.
r_t = Thermal resistance at time t.
r_p = Amplitude of p_{th} term.
τ_p = Time Constant of r_{th} term.

D.C. Double Side Cooled			
Term	1	2	3
r_p	2.761048×10^{-3}	1.738044×10^{-3}	5.209655×10^{-4}
τ_p	0.8332002	0.1416775	0.01436119

D.C. Cathode Side Cooled			
Term	1	2	3
r_p	9.855141×10^{-3}	1.983482×10^{-3}	4.775474×10^{-4}
τ_p	4.147275	0.1396446	0.0116827

Curves

Figure 1 - On-state characteristics of Limit device

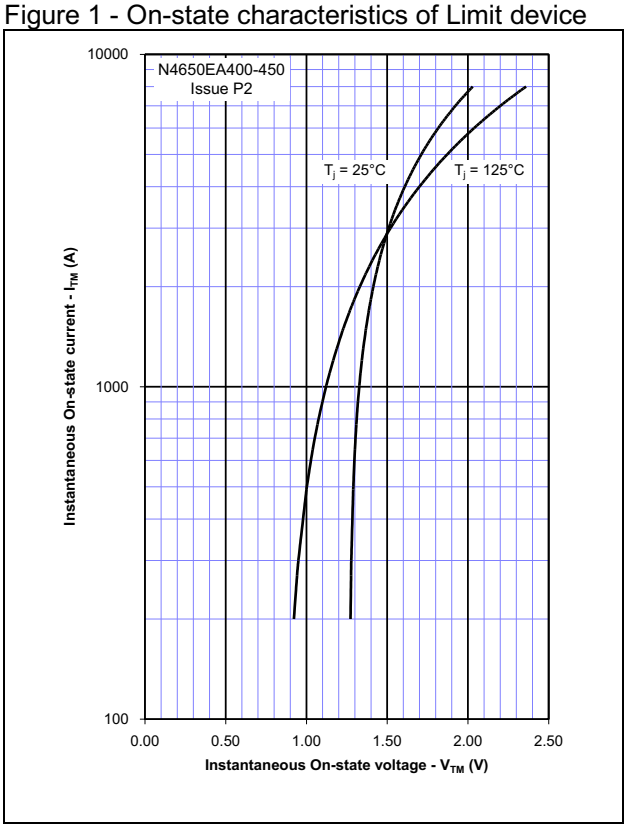


Figure 2 - Transient Thermal Impedance

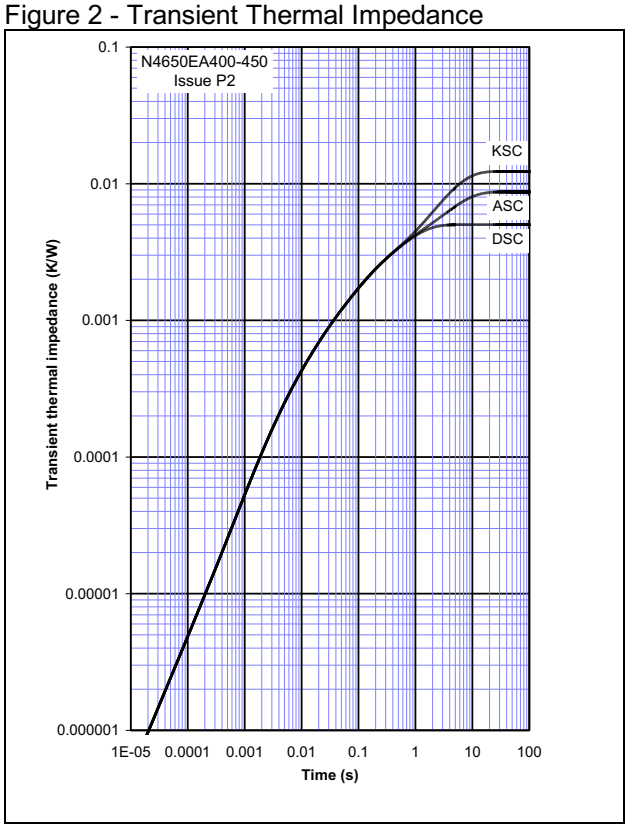


Figure 3 - Gate Characteristics - Trigger Limits

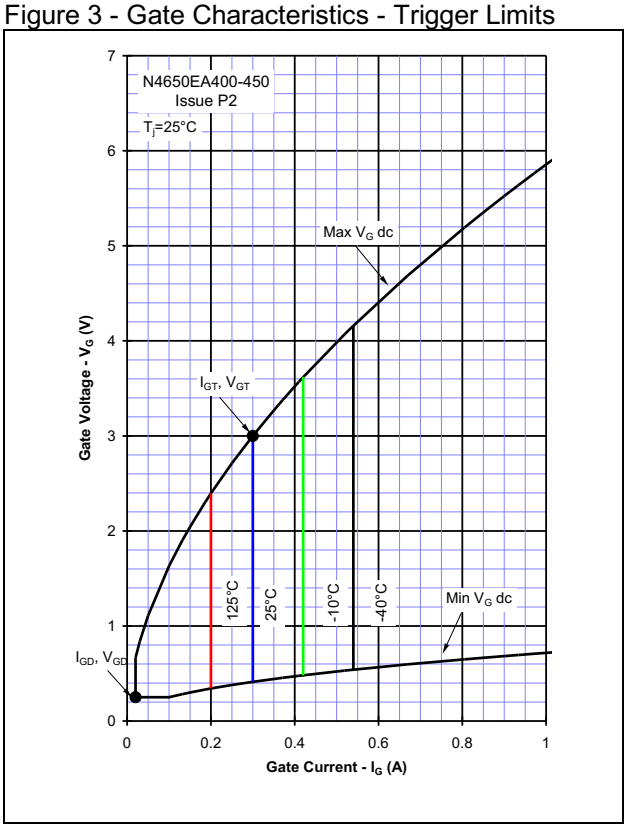


Figure 4 - Gate Characteristics - Power Curves

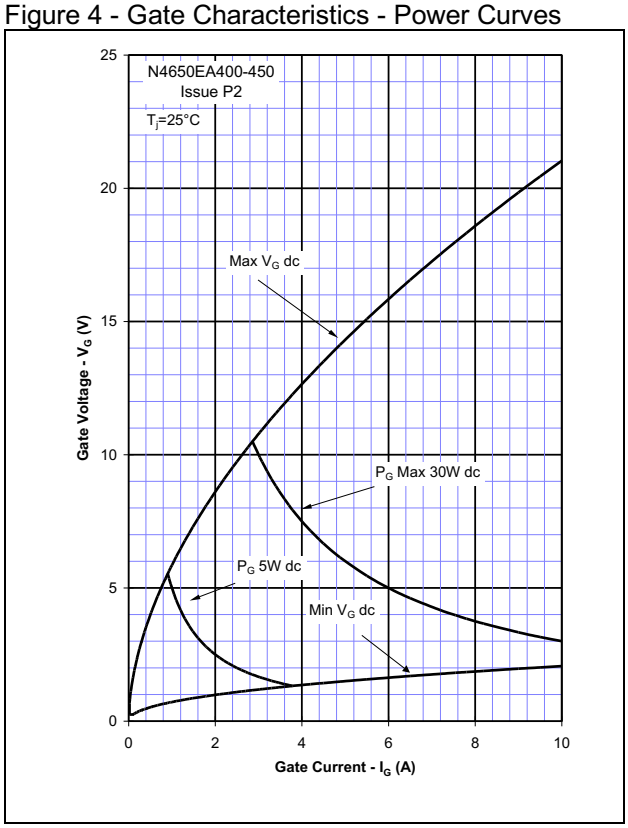


Figure 5 – Recovered Charge, Q_{rr}

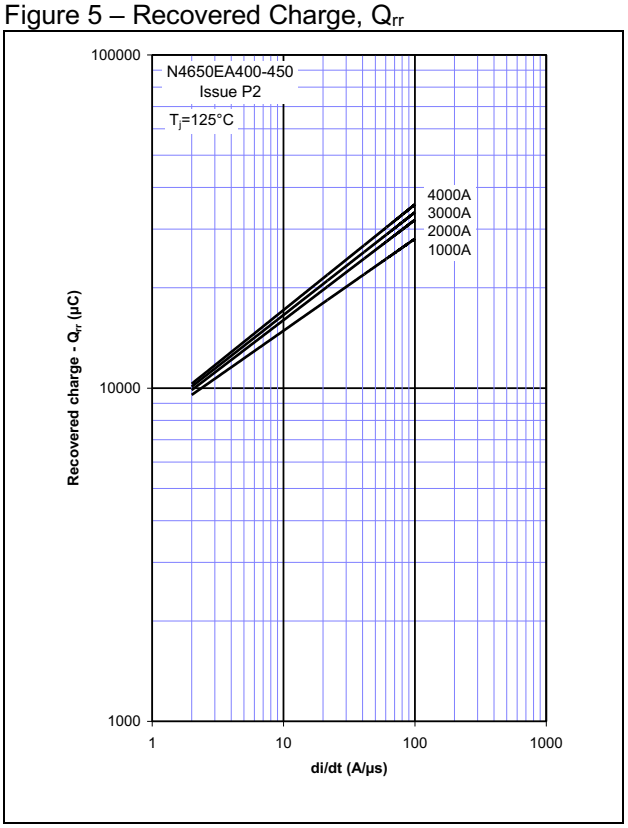


Figure 6 – Recovered charge, Q_{ra} (50% chord)

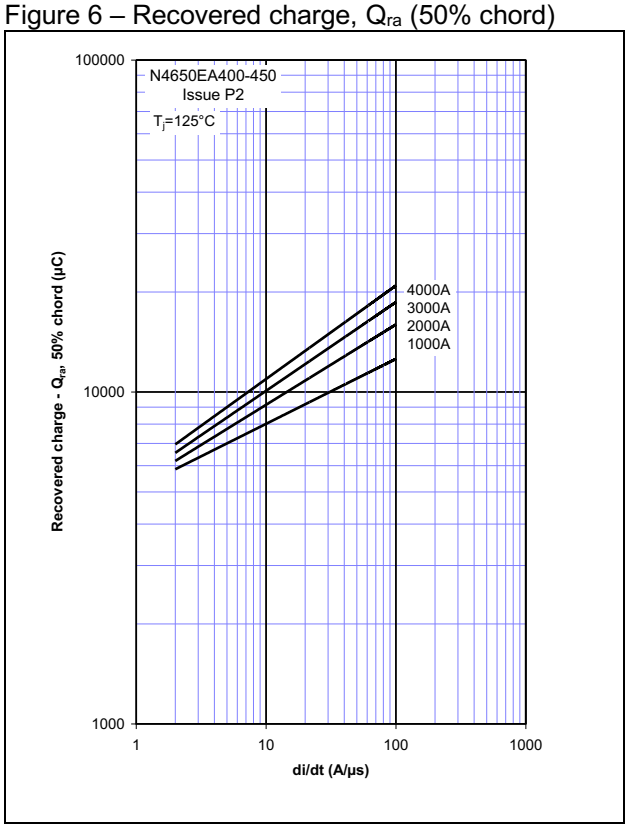


Figure 7 – Reverse recovery current, I_{rm}

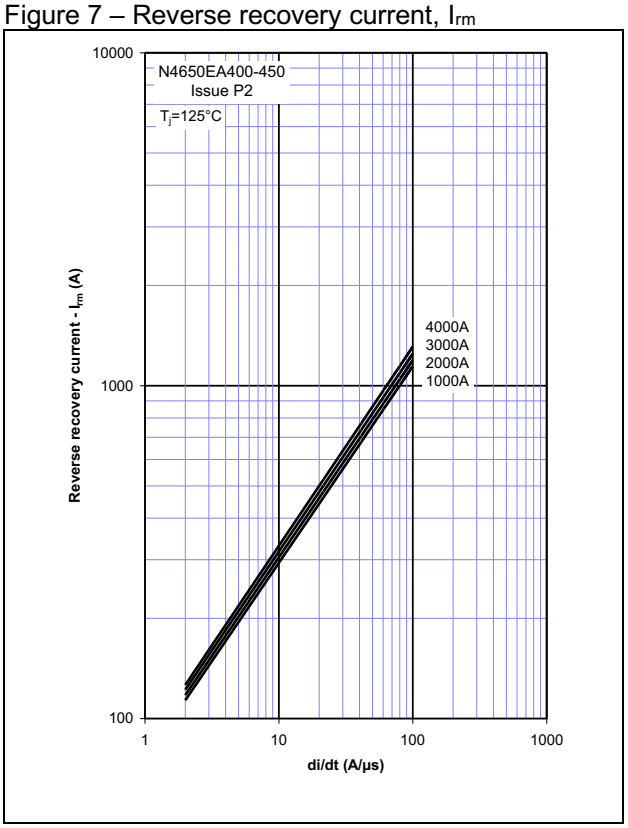


Figure 8 – Reverse recovery time, t_{rr}

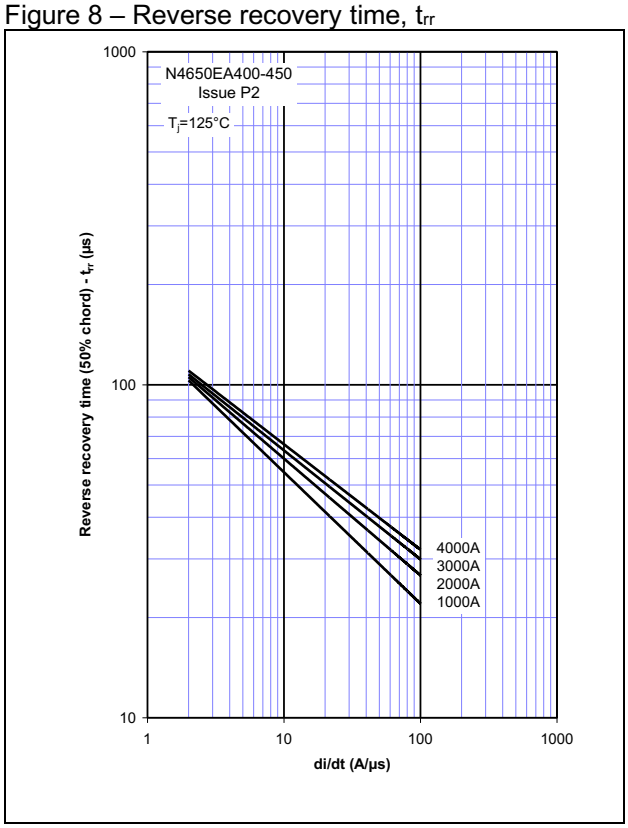


Figure 9 – On-state current vs. Power dissipation – Double Side Cooled (Sine wave)

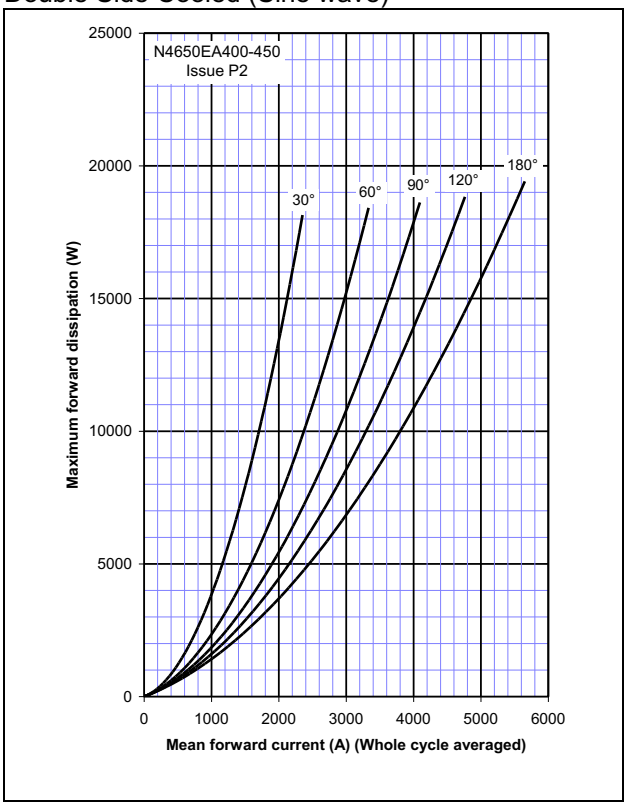


Figure 10 – On-state current vs. Heatsink temperature - Double Side Cooled (Sine wave)

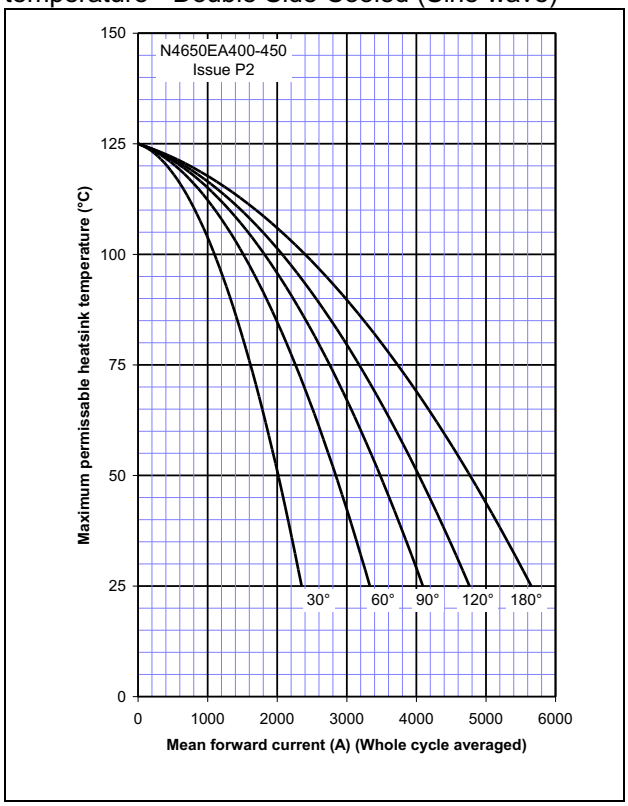


Figure 11 – On-state current vs. Power dissipation – Double Side Cooled (Square wave)

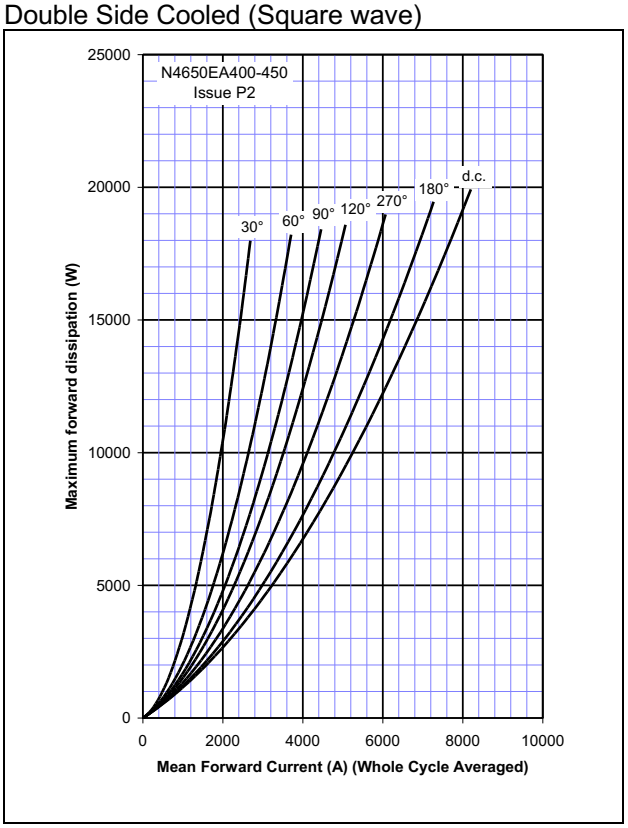


Figure 12 – On-state current vs. Heatsink temperature - Double Side Cooled (Square wave)

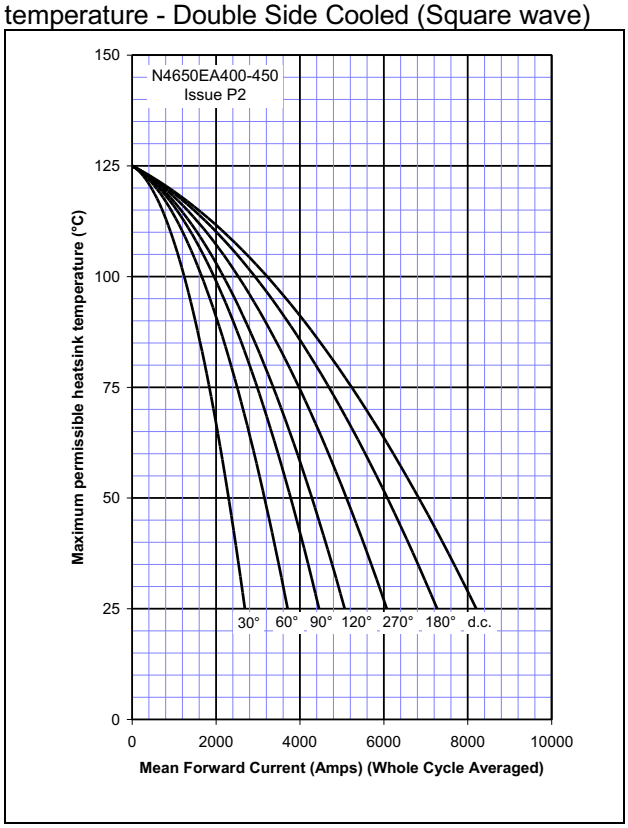


Figure 13 – On-state current vs. Power dissipation – Cathode Side Cooled (Sine wave)

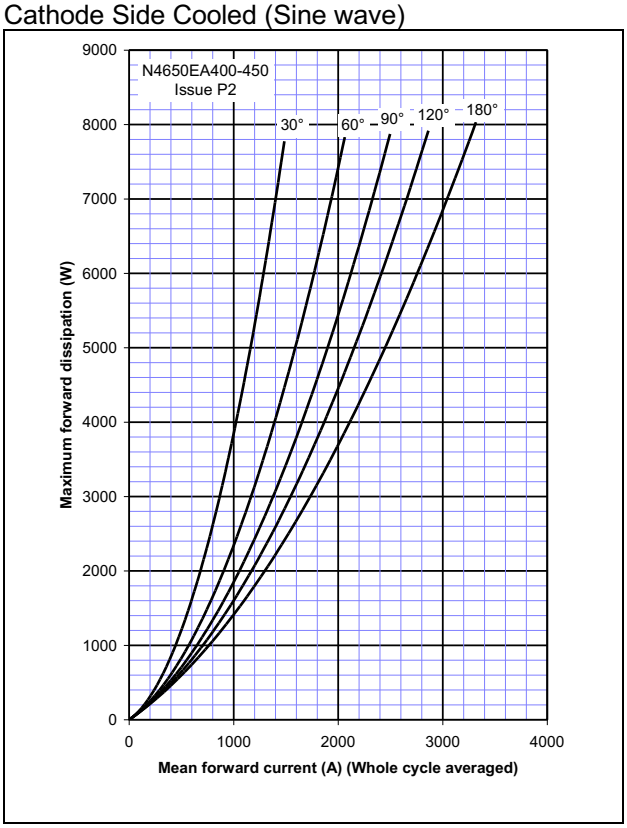


Figure 14 – On-state current vs. Heatsink temperature - Cathode Side Cooled (Sine wave)

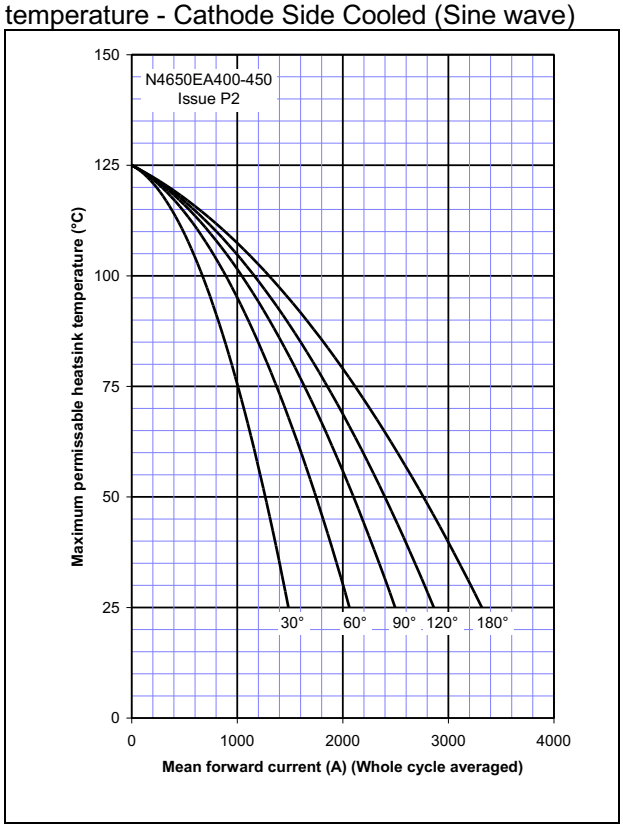


Figure 15 – On-state current vs. Power dissipation – Cathode Side Cooled (Square wave)

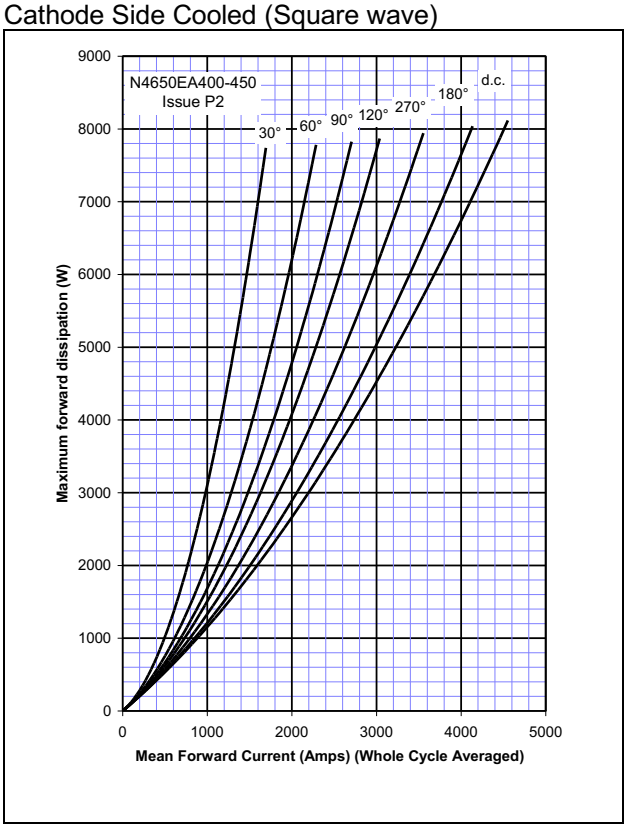


Figure 16 – On-state current vs. Heatsink temperature - Cathode Side Cooled (Square wave)

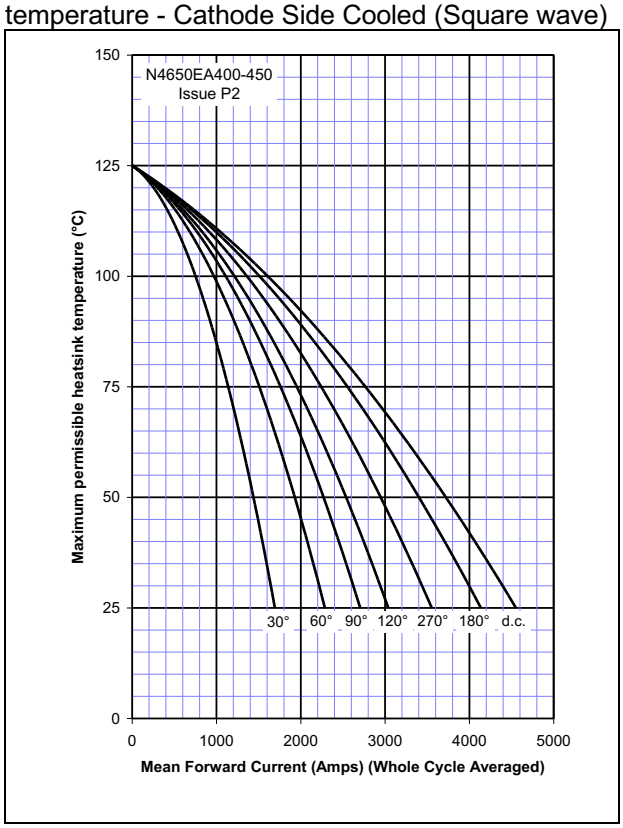
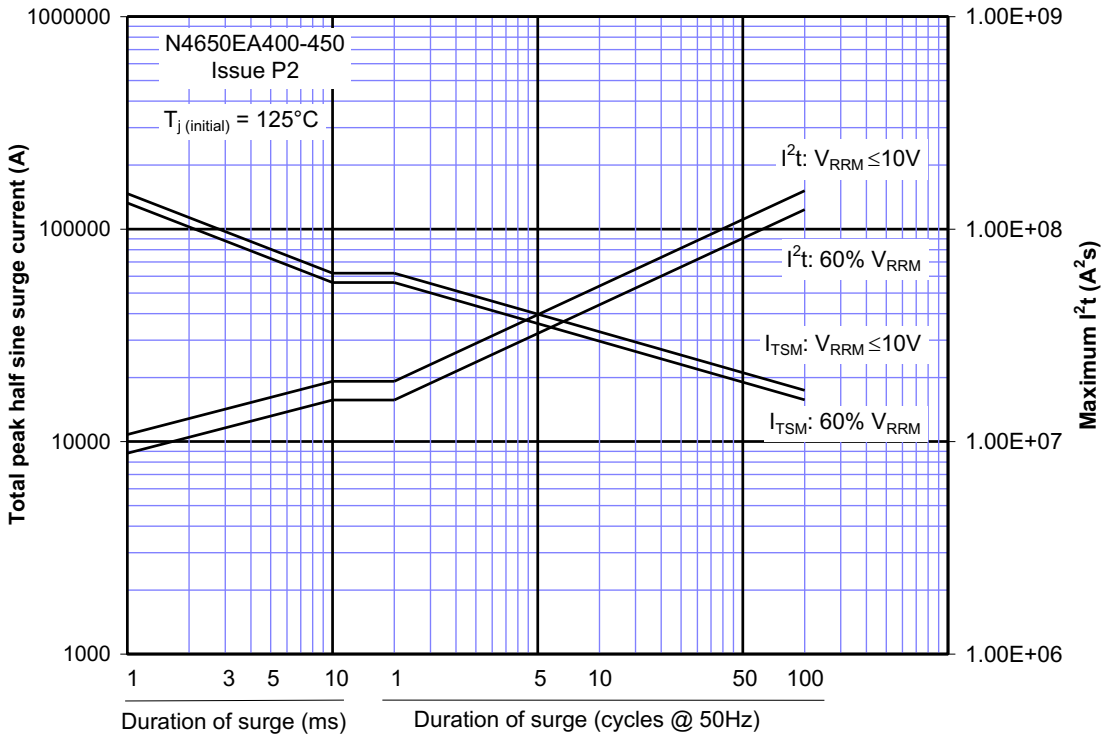
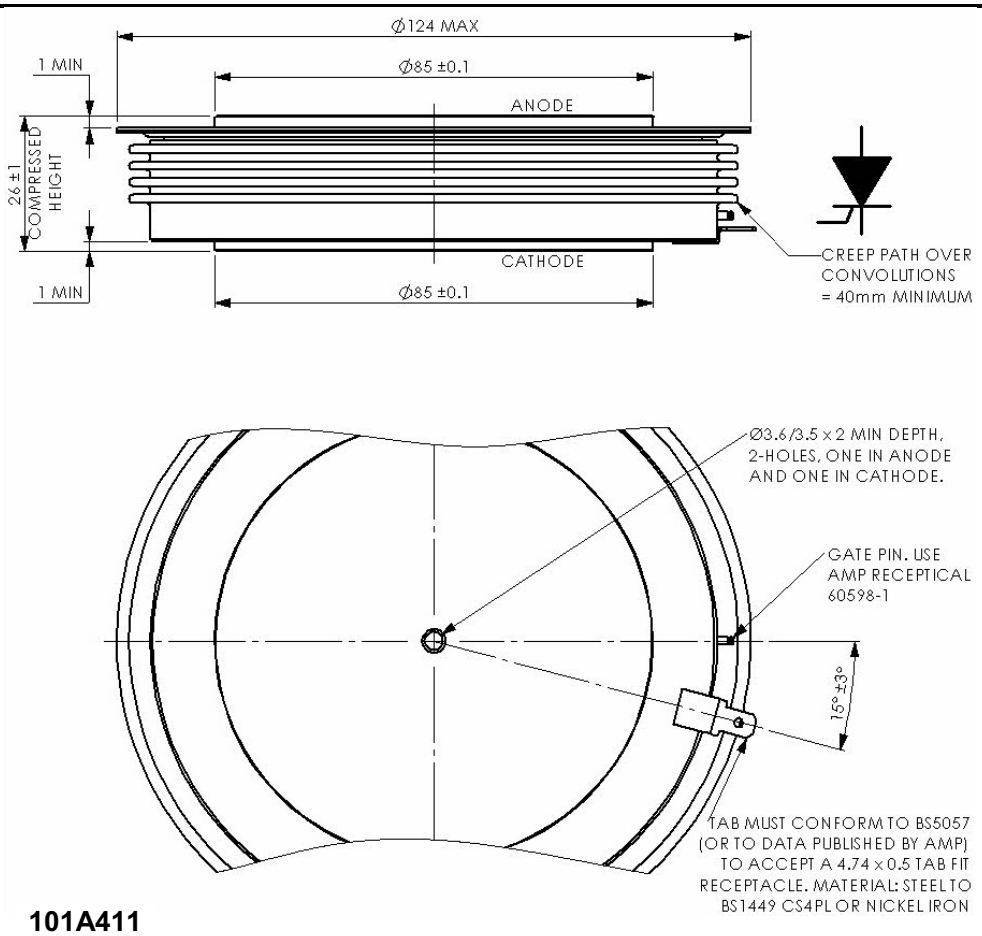


Figure 17 – Maximum surge and I^2t Ratings



Outline Drawing & Ordering Information



101A411

ORDERING INFORMATION (Please quote 10 digit code as below)

N4650	EA	♦ ♦	0
Fixed Type Code	Fixed Outline Code	Voltage Code 40 & 45	Fixed turn-off time code

Typical order code: N4650EA450 – 4500V V_{DRM}, V_{RRM}, 1000V/µs dv/dt, 26mm clamp height capsule.

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